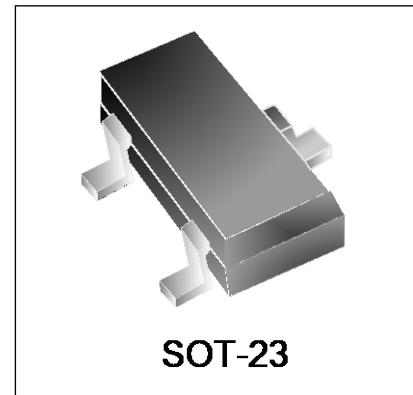


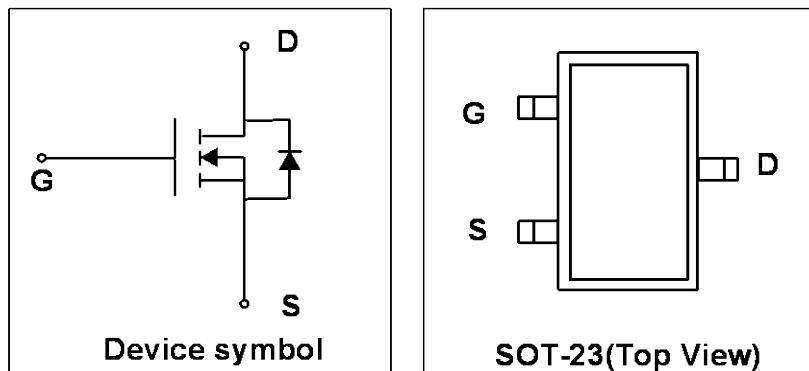
## N-Channel Enhancement MOSFET

**Features**

- Way-on Small Signal MOSFETs
- $V_{DS} = 100V$ ,  $I_D = 2A$
- $R_{DS(on)} < 280m\Omega$  @  $V_{GS} = 10V$
- $R_{DS(on)} < 310m\Omega$  @  $V_{GS} = 4.5V$
- Trench LV MOSFET Technology

**Mechanical Characteristics**

- SOT-23 Package
- Marking : Making Code
- RoHS Compliant

**Schematic & PIN Configuration****Absolute Maximum Rating ( $T_A=25^\circ C$  unless otherwise noted)**

| Parameter                                        | Symbol         | Value      | Unit       |
|--------------------------------------------------|----------------|------------|------------|
| Drain-Source Voltage                             | $V_{DS}$       | 100        | V          |
| Gate-Source Voltage                              | $V_{GS}$       | $\pm 20$   | V          |
| Continuous Drain Current<br>$T_A = 25^\circ C$   | $I_D$          | 2          | A          |
| Pulsed Drain Current <sup>1</sup>                | $I_{DM}$       | 8          | A          |
| Power Dissipation<br>$T_A = 25^\circ C$          | $P_D$          | 1.2        | W          |
| Operating Junction and Storage Temperature Range | $T_J, T_{STG}$ | -55 to 150 | $^\circ C$ |

**Thermal Characteristics**

| Parameter                                                | Symbol   | Value | Unit         |
|----------------------------------------------------------|----------|-------|--------------|
| Thermal Resistance from Junction to Ambient <sup>2</sup> | $R_{JA}$ | 105   | $^\circ C/W$ |

**Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise specified)**

| Parameter                                     | Symbol               | Test Condition                                                                            | Min. | Typ. | Max. | Unit |
|-----------------------------------------------|----------------------|-------------------------------------------------------------------------------------------|------|------|------|------|
| <b>Static Characteristics</b>                 |                      |                                                                                           |      |      |      |      |
| Drain-Source Breakdown Voltage                | V <sub>(BR)DSS</sub> | V <sub>GS</sub> = 0 V, I <sub>D</sub> = 250µA                                             | 100  | -    | -    | V    |
| Gate Leakage Current                          | I <sub>GSS</sub>     | V <sub>GS</sub> = ±20V, V <sub>DS</sub> = 0V                                              | -    | -    | ±100 | nA   |
| Drain Cut-off Current                         | I <sub>DSS</sub>     | V <sub>DS</sub> = 100V, V <sub>GS</sub> = 0V                                              | -    | -    | 1    | µA   |
| Gate Threshold Voltage                        | V <sub>GS(th)</sub>  | V <sub>GS</sub> = V <sub>DS</sub> , I <sub>D</sub> = 250µA                                | 1    | 1.5  | 2    | V    |
| Drain-Source on-state Resistance <sup>3</sup> | R <sub>Ds(on)</sub>  | V <sub>GS</sub> = 10V, I <sub>D</sub> = 2A                                                | -    | 220  | 280  | mΩ   |
|                                               |                      | V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 1.5A                                             | -    | 240  | 310  |      |
| <b>Dynamic Characteristics<sup>4</sup></b>    |                      |                                                                                           |      |      |      |      |
| Input Capacitance                             | C <sub>iss</sub>     | V <sub>GS</sub> = 0V, V <sub>DS</sub> = 50V,<br>f = 1MHz                                  | -    | 440  | -    | pF   |
| Output Capacitance                            | C <sub>oss</sub>     |                                                                                           | -    | 14   | -    |      |
| Reverse Transfer Capacitance                  | C <sub>rss</sub>     |                                                                                           | -    | 10   | -    |      |
| <b>Switching Characteristics<sup>4</sup></b>  |                      |                                                                                           |      |      |      |      |
| Total gate charge                             | Q <sub>g</sub>       | V <sub>GS</sub> = 10V, V <sub>DS</sub> = 50V,<br>I <sub>D</sub> = 2A                      | -    | 5.3  | -    | nC   |
| Gate-source charge                            | Q <sub>gs</sub>      |                                                                                           | -    | 1.4  | -    |      |
| Gate-drain charge                             | Q <sub>gd</sub>      |                                                                                           | -    | 1.8  | -    |      |
| Turn-on Time                                  | t <sub>d(on)</sub>   | V <sub>GS</sub> = 10V, V <sub>DD</sub> = 50V,<br>R <sub>G</sub> = 1Ω, I <sub>D</sub> = 2A | -    | 14   | -    | ns   |
| Rise time                                     | t <sub>f</sub>       |                                                                                           | -    | 54   | -    |      |
| Turn-off Time                                 | t <sub>d(off)</sub>  |                                                                                           | -    | 18   | -    |      |
| Fall time                                     | t <sub>f</sub>       |                                                                                           | -    | 11   | -    |      |
| <b>Source-Drain Diode characteristics</b>     |                      |                                                                                           |      |      |      |      |
| Body Diode Voltage <sup>3</sup>               | V <sub>SD</sub>      | I <sub>S</sub> = 1A, V <sub>GS</sub> = 0V                                                 | -    | -    | 1.2  | V    |
| Continuous Source Current                     | I <sub>S</sub>       |                                                                                           | -    | -    | 2    | A    |

**Notes:**

1. Repetitive rating, pulse width limited by junction temperature T<sub>J(MAX)</sub>=150°C.
2. The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper, The value in any given application depends on the user's specific board design.
3. Pulse Test: Pulse width≤300µs, duty cycle≤2%.
4. This value is guaranteed by design hence it is not included in the production test.

## Typical Characteristics

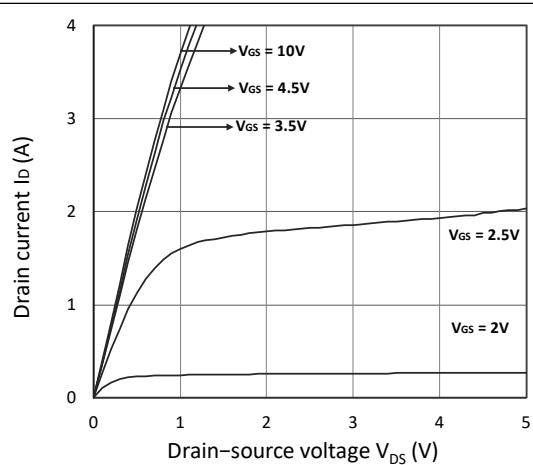


Figure 1. Output Characteristics

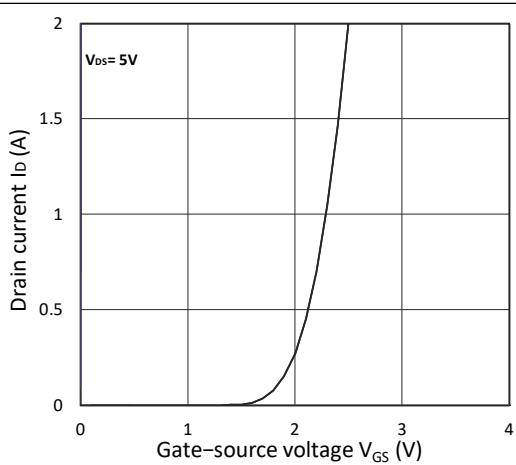


Figure 2. Transfer Characteristics

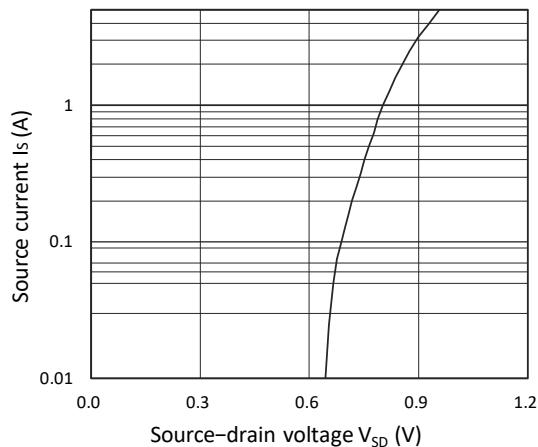
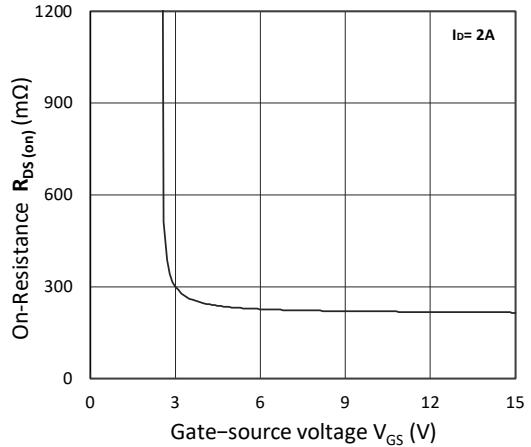
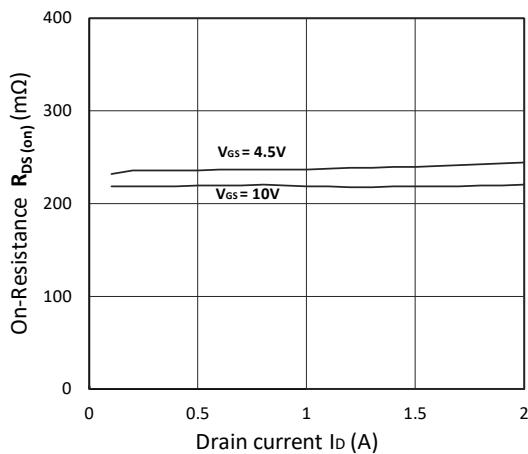
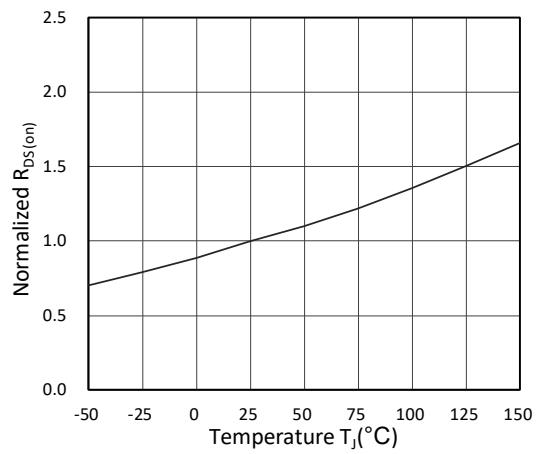


Figure 3. Forward Characteristics of Reverse

Figure 4.  $R_{DS(ON)}$  vs.  $V_{GS}$ Figure 5.  $R_{DS(ON)}$  vs.  $I_D$ Figure 6. Normalized  $R_{DS(on)}$  vs. Temperature

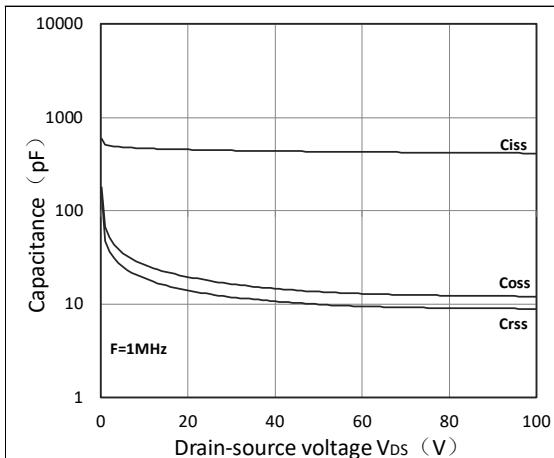


Figure 7. Capacitance Characteristics

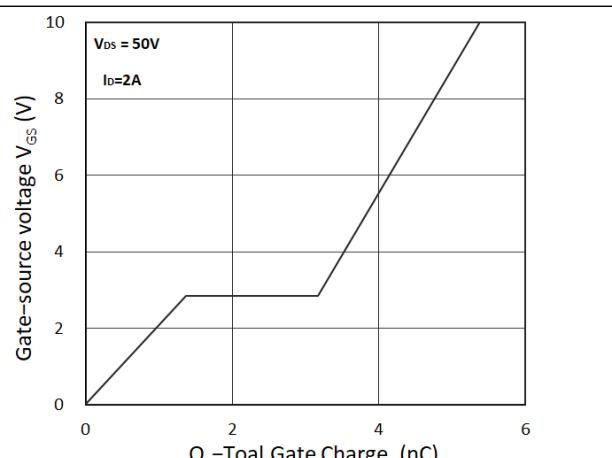
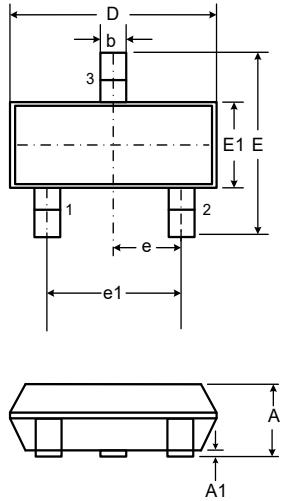
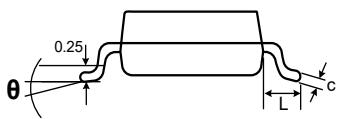
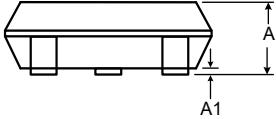
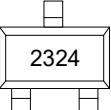


Figure 8. Gate Charge Characteristics

## Outline Drawing – SOT-23

| PACKAGE OUTLINE                                                                   |            |                                                                                   |           |       |
|-----------------------------------------------------------------------------------|------------|-----------------------------------------------------------------------------------|-----------|-------|
|  |            |  |           |       |
|  |            |                                                                                   |           |       |
| DIMENSIONS                                                                        |            |                                                                                   |           |       |
| SYMBOL                                                                            | MILLIMETER |                                                                                   | INCHES    |       |
|                                                                                   | MIN        | MAX                                                                               | MIN       | MAX   |
| A                                                                                 | 0.90       | 1.15                                                                              | 0.035     | 0.045 |
| A1                                                                                | 0.00       | 0.10                                                                              | 0.000     | 0.004 |
| b                                                                                 | 0.30       | 0.50                                                                              | 0.012     | 0.020 |
| c                                                                                 | 0.08       | 0.15                                                                              | 0.003     | 0.006 |
| D                                                                                 | 2.80       | 3.00                                                                              | 0.110     | 0.118 |
| E                                                                                 | 2.25       | 2.55                                                                              | 0.089     | 0.100 |
| E1                                                                                | 1.20       | 1.40                                                                              | 0.047     | 0.055 |
| e                                                                                 | 0.95 BSC   |                                                                                   | 0.037 BSC |       |
| e1                                                                                | 1.80       | 2.00                                                                              | 0.071     | 0.079 |
| L                                                                                 | 0.55REF    |                                                                                   | 0.022REF  |       |
| θ                                                                                 | 0          | 8                                                                                 | 0         | 8     |
| Notes                                                                             |            |                                                                                   |           |       |
| 1. Dimensioning and tolerances per ANSI Y14.5M, 1985.                             |            |                                                                                   |           |       |
| 2. Controlling Dimension: Inches                                                  |            |                                                                                   |           |       |
| 3. Pin 3 is the cathode (Unidirectional Only).                                    |            |                                                                                   |           |       |
| 4. Dimensions are exclusive of mold flash and metal burrs.                        |            |                                                                                   |           |       |

## Marking Codes

|              |                                                                                     |
|--------------|-------------------------------------------------------------------------------------|
| Part Number  | WM10N20M                                                                            |
| Marking Code |  |

## Package Information

Qty: 3k/Reel

## CONTACT INFORMATION

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WAYON website: <http://www.way-on.com>

For additional information, please contact your local Sales Representative.

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Specifications are subject to change without notice.

The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time. Users should verify actual device performance in their specific applications.